

RJK1211DNS

Silicon N Channel Power MOS FET Power Switching

R07DS0090EJ0300 Rev.3.00 Feb 01, 2012

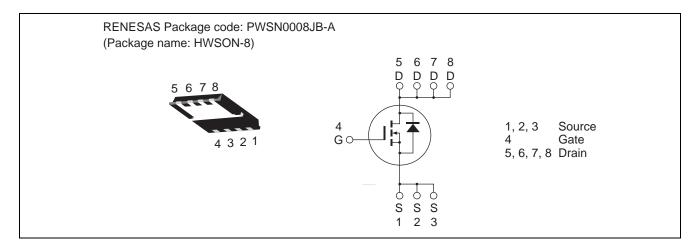
Features

- High speed switching
- Capable of 4.5 V gate drive
- Low drive current
- High density mounting
- Low on-resistance

 $R_{DS(on)} \! = 100 \; m\Omega$ typ. (at $V_{GS} \! = 10 \; V)$

- Pb-free
- Halogen-free

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	Ratings	Unit
Drain to source voltage	V _{DSS}	120	V
Gate to source voltage	V _{GSS}	+12, -5	V
Drain current	I _D	5	A
Drain peak current	I _{D(pulse)} Note1	15	A
Body-drain diode reverse drain current	I _{DR}	5	A
Avalanche current	I _{AP} Note 2	3	A
Avalanche energy	E _{AR} Note 2	0.77	mJ
Channel dissipation	Pch Note3	10	W
Channel to case thermal impedance	θch-c Note3	12.5	°C/W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

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Notes: 1. PW \leq 10 μ s, duty cycle \leq 1%

- 2. Value at Tch = 25°C, Rg \geq 50 Ω
- 3. Tc = 25°C

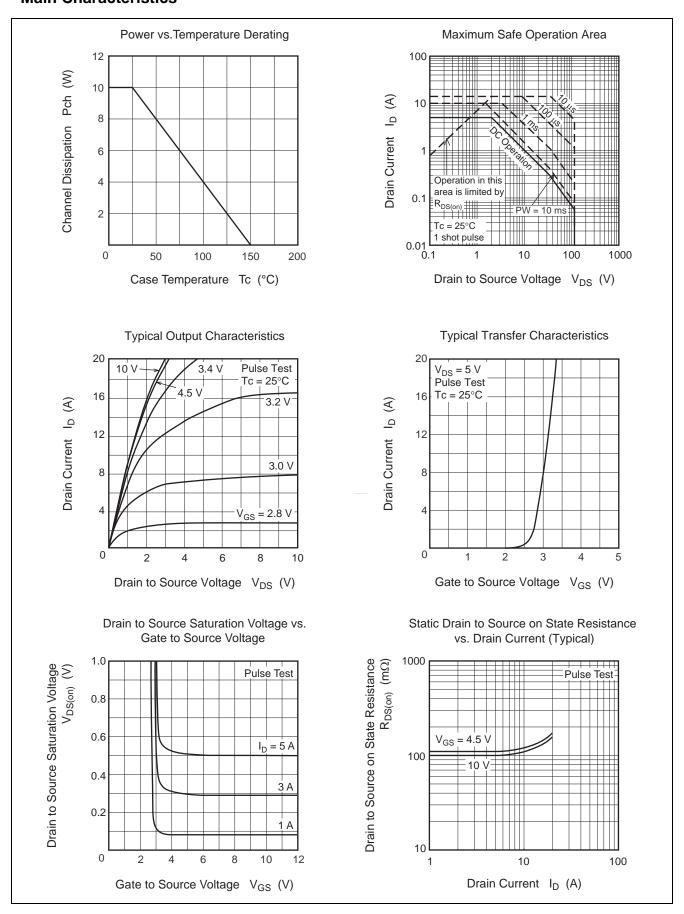
Electrical Characteristics

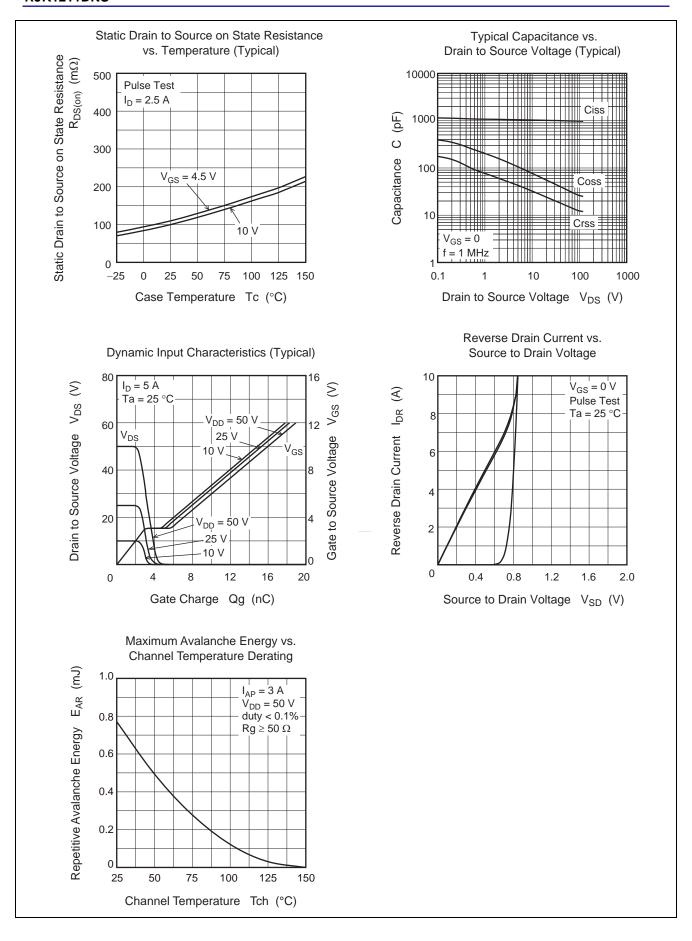
 $(Ta = 25^{\circ}C)$

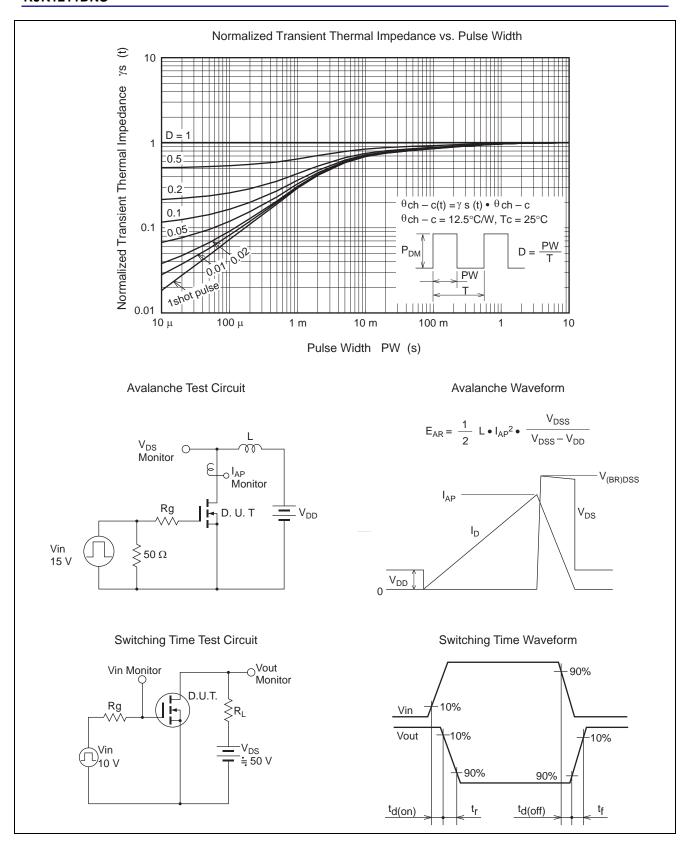
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	120	_	_	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Gate to source leak current	I _{GSS}	_	_	± 0.1	μΑ	$V_{GS} = +12, -5 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	I _{DSS}	_	_	10	μА	$V_{DS} = 120 \text{ V}, V_{GS} = 0$
Gate to source cutoff voltage	V _{GS(off)}	1.2	_	2.5	V	$V_{DS} = 10 \text{ V}, I_{D} = 1 \text{ mA}$
Static drain to source on state	R _{DS(on)}	_	100	130	mΩ	$I_D = 2.5 \text{ A}, V_{GS} = 10 \text{ V}^{\text{Note4}}$
resistance	R _{DS(on)}	_	110	150	mΩ	$I_D = 2.5 \text{ A}, V_{GS} = 4.5 \text{ V}^{\text{Note4}}$
Forward transfer admittance	y _{fs}	_	9.0	_	S	$I_D = 2.5 \text{ A}, V_{DS} = 5 \text{ V}^{\text{Note4}}$
Input capacitance	Ciss	_	1070	_	рF	$V_{DS} = 10 \text{ V}$
Output capacitance	Coss	_	80	_	рF	$V_{GS} = 0$ f = 1 MHz
Reverse transfer capacitance	Crss	_	35	_	рF	
Gate Resistance	Rg	_	1.7	_	Ω	
Total gate charge	Qg	_	8.0	_	nC	$V_{DD} = 50 \text{ V}$ $V_{GS} = 4.5 \text{ V}$ $I_{D} = 5 \text{ A}$
Gate to source charge	Qgs	_	3.0	_	nC	
Gate to drain charge	Qgd	_	2.0	_	nC	
Turn-on delay time	t _{d(on)}	_	7.8	_	ns	$V_{GS} = 10 \text{ V}, I_D = 2.5 \text{ A}$
Rise time	t _r	_	2.8	_	ns	$V_{DD} \cong 30 \text{ V}$ $R_L = 12 \Omega$ $Rg = 4.7 \Omega$
Turn-off delay time	t _{d(off)}	_	38	_	ns	
Fall time	t _f	_	2.7	_	ns	
Body-drain diode forward voltage	V_{DF}	_	0.83	1.1	V	$I_F = 5 \text{ A}, V_{GS} = 0^{\text{Note4}}$
Body-drain diode reverse recovery	t _{rr}	_	40	_	ns	$I_F = 5 \text{ A}, V_{GS} = 0$
time						$di_F/dt = 100 A/ \mu s$

Notes: 4. Pulse test

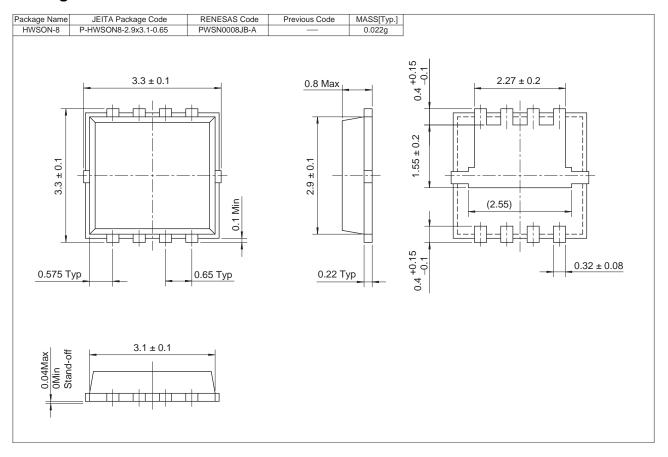
Main Characteristics







Package Dimensions



Ordering Information

Orderable Part Number	Quantity	Shipping Container
RJK1211DNS-00-J5	5000 pcs	Taping

Note: The symbol of 2nd "-" is occasionally presented as "#".

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